

April 1988 Revised August 1999

# 74F366•74F368 Hex Inverter Buffer with 3-STATE Outputs

#### **Features**

■ 3-STATE buffer outputs sink 64 mA

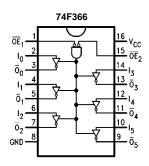
- High-speed
- Bus-oriented
- $\blacksquare$  High impedance npn base inputs for reduced loading

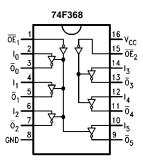
#### **Ordering Code:**

Order Number	Package Number	Package Description
74F366SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F366PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F368SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F368SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F368PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

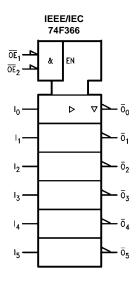
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

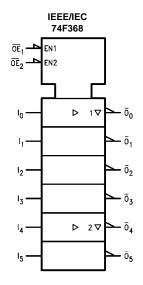
#### **Connection Diagrams**





# **Logic Symbols**





# **Unit Loading/Fan Out**

Din Name	Decembris	U.L.	Input I <sub>IH</sub> /I <sub>IL</sub>	
Pin Names	Description	HIGH/LOW	Output I <sub>OH</sub> /I <sub>OL</sub>	
$\overline{OE}_1$ , $\overline{OE}_2$	Output Enable Input (Active LOW)	1.0/0.033	20 μΑ/–20 μΑ	
In	Input	1.0/0.033	20 μΑ/–20 μΑ	
$O_n, \overline{O}_n$	Outputs	600/106.6 (80)	-12 mA/64 mA (48 mA)	

# **Function Tables**

74F366

	Output		
OE <sub>1</sub>	OE <sub>2</sub>	ı	О
L	L	L	Н
L	L	Н	L
X	Н	Χ	Z
Н	Χ	Χ	Z

#### 74F368

Inp	uts	Output		
ŌĒ	ı	ō		
L	L	Н		
L	Н	L		
Н	Х	Z		

$$\label{eq:lower_lower} \begin{split} L = & \mbox{LOW Voltage Level} & X = \mbox{Immaterial} \\ H = & \mbox{HIGH Voltage Level} & Z = \mbox{High Impedance} \end{split}$$

#### **Absolute Maximum Ratings**(Note 1)

–65°C to +150°C

Ambient Temperature under Bias  $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  Junction Temperature under Bias  $-55^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ 

 $V_{CC}$  Pin Potential to Ground Pin -0.5V to +7.0V Input Voltage (Note 2) -0.5V to +7.0V Input Current (Note 2) -30 mA to +5.0 mA

Voltage Applied to Output

Storage Temperature

in HIGH State (with  $V_{CC} = 0V$ )

Standard Output -0.5V to V<sub>CC</sub> 3-STATE Output -0.5V to +5.5V

Current Applied to Output

in LOW State (Max) twice the rated I<sub>OL</sub> (mA)

# Recommended Operating Conditions

Free Air Ambient Temperature  $0^{\circ}$ C to  $+70^{\circ}$ C Supply Voltage +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation

under these conditions is not implied.

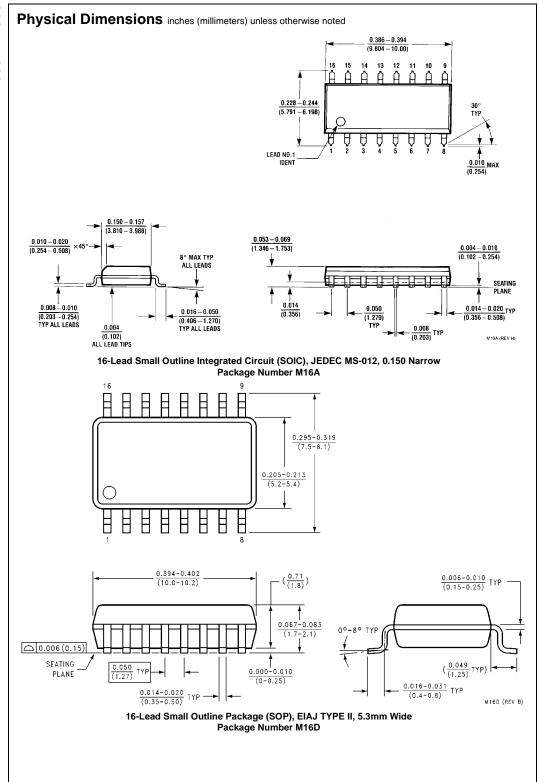
Note 2: Either voltage limit or current limit is sufficient to protect inputs.

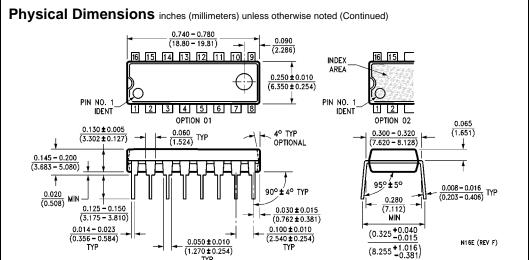
#### **DC Electrical Characteristics**

Symbol	Parameter	Min	Тур	Max	Units	V <sub>cc</sub>	Conditions
V <sub>IH</sub>	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V <sub>IL</sub>	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V <sub>CD</sub>	Input Clamp Diode Voltage			-1.2	V	Min	I <sub>IN</sub> = -18 mA
V <sub>OH</sub>	Output HIGH 10% V <sub>CC</sub>	2.0			V	Min	I <sub>OH</sub> = -15 mA
	Voltage						
V <sub>OL</sub>	Output LOW 10% V <sub>CC</sub>			0.55	V	Min	I <sub>OL</sub> = 64 mA
	Voltage						
I <sub>IH</sub>	Input HIGH Current			20	μΑ	Max	V <sub>IN</sub> = 2.7V
I <sub>BVI</sub>	Input HIGH Current			100	μΑ	Max	V <sub>IN</sub> = 7.0V
	Breakdown Test						
I <sub>IL</sub>	Input LOW Current			-20	μΑ	Max	V <sub>IN</sub> = 0.5V
l <sub>OZH</sub>	Output Leakage Current			50	μΑ	Max	V <sub>OUT</sub> = 2.7V
I <sub>OZL</sub>	Output Leakage Current			-50	μΑ	Max	V <sub>OUT</sub> = 0.5V
Ios	Output Short-Circuit Current	-100		-225	mA	Max	V <sub>OUT</sub> = 0V
I <sub>CEX</sub>	Output HIGH Leakage Current			250	μΑ	Max	$V_{OUT} = V_{CC}$
I <sub>ZZ</sub>	Bus Drainage Test			500	μΑ	0.0V	V <sub>OUT</sub> = 5.25V
I <sub>CCH</sub>	Power Supply Current		20	25	mA	Max	V <sub>O</sub> = HIGH
I <sub>CCL</sub>	Power Supply Current		49	62	mA	Max	$V_O = LOW$
I <sub>CCZ</sub>	Power Supply Current		35	48	mA	Max	V <sub>O</sub> = HIGH Z

#### **AC Electrical Characteristics**

Symbol	Parameter	$T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			$T_A = 0$ °C to +70°C $C_L = 50$ pF $C_L = 50$ pF		Units
İ		Min	Тур	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay	2.5	4.0	6.5	2.0	7.5	
t <sub>PHL</sub>		1.0	1.8	5.0	1.0	5.5	ns
t <sub>PZH</sub>	Enable Time (74F366)	2.5	4.2	9.5	2.5	10.0	ns
t <sub>PZL</sub>		2.5	4.2	9.0	2.5	9.5	115
t <sub>PZH</sub>	Enable Time (74F368)	2.5	4.2	7.5	2.0	8.5	ns
t <sub>PZL</sub>		3.0	5.6	8.5	3.0	9.0	115
t <sub>PHZ</sub>	Disable Time	2.0	3.3	6.5	2.0	7.0	ns
t <sub>PLZ</sub>		2.0	4.1	6.5	2.0	7.0	115





16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide Package Number N16E

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